

Supplementary Materials for

Single-particle mapping of nonequilibrium nanocrystal transformations

Xingchen Ye, Matthew R. Jones, Layne B. Frechette, Qian Chen, Alexander S. Powers, Peter Ercius, Gabriel Dunn, Grant M. Rotskoff, Son C. Nguyen, Vivekananda P. Adiga, Alex Zettl, Eran Rabani, Phillip L. Geissler, A. Paul Alivisatos*

*Corresponding author. Email: alivis@berkeley.edu

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Materials and Methods

Nomenclature

Here we use the terminology laid out in (33) where specific crystallographic planes and directions are denoted by parenthesis and square brackets, respectively (e.g. (100) plane and [110] direction) while families of planes and families of directions that are related by symmetry are denoted by curly brackets and angled brackets, respectively (e.g. {100} planes and $\langle 110 \rangle$ directions).

Nanocrystal synthesis

Gold nanorods (34, 35), pentagonal bipyramids (36), triangular prisms (37), decahedra (37), cubes (7), rhombic dodecahedra (7), and octahedra (7) were synthesized according to previously reported methods. Nanocrystals were cleaned by two rounds of centrifugation at 6000 rpm for 15 min and were finally dispersed in Milli-Q water (18.2 M Ω ·cm) with a concentration characterized by an optical density (OD) of 5-8 at the peak of their plasmonic resonance.

Preparation of graphene-coated TEM grids

Single-layer graphene was grown on copper foil by chemical vapor deposition. Selective removal of graphene from one side of the copper foil was achieved using mild oxygen plasma treatment. Individual 300-mesh Quantifoil gold TEM grids (Structural Probe, Inc. Catalog number: 4230G-XA) were placed on top of a piece of graphene-covered copper foil with the amorphous carbon film side facing the graphene. 15 μ L of isopropanol was then dropped onto the copper foil to wet the interface between the graphene and the amorphous carbon film of the TEM grid (as isopropanol evaporates, the graphene layer becomes bound to the Quantifoil TEM grid). Then, the copper foil with adhered TEM grids on top was floated on a 0.1 g/mL aqueous solution of sodium persulfate (Sigma Aldrich) to etch the underlying copper foil. These graphene-coated TEM grids were subsequently rinsed with deionized water three times to remove the residual etching solution, and were left dry in air for further use.

Encapsulation of solution samples in graphene liquid cells (GLCs)

Two 50 mL aqueous solutions of 0.01 M Tris buffer (Fisher Scientific) and 0.1 M FeCl₃ (Sigma Aldrich) were prepared separately. 90 µL of hydrochloric acid (HCl, 37 wt. % in water, 12.1 M) was added to the 50 mL of 0.1 M FeCl₃ solution to suppress the hydrolysis of FeCl₃. The pH of this acidified 0.1 M FeCl₃ stock solution was determined to be 0.65 ± 0.02 by measuring six independently prepared solutions with an Accumet pH meter (Fisher Scientific). For nanocrystal etching experiments, unless otherwise specified, 0.6 mL of the acidified 0.1 M FeCl3 solution was mixed with 0.9 mL of 0.01 M Tris buffer solution, to which 15 µL of an aqueous solution of gold nanocrystals was added. This resulted in a final nanocrystal concentration of 0.05-0.08 OD and a final pH of 0.92 ± 0.02 in the solution intended for encapsulation in graphene liquid cells. For experiments with different concentrations of FeCl₃, a certain volume of 0.1 M FeCl₃ solution was used and the volume of 0.01 M Tris buffer solution was adjusted accordingly to maintain the total volume to be 1.5 mL. In some control experiments, isopropanol was deliberately introduced to a final concentration of 0.15 M, as it is a known scavenger of oxidative species (11, 38). To encapsulate liquid samples in graphene liquid cells, one graphene-coated TEM grid was first laid onto a glass slide with the graphene side facing upwards. Next, a small droplet of the aforementioned nanocrystal-etchant-Tris buffer solution was placed onto the central region of the TEM gird. Then, another graphene-coated TEM grid was gently placed on top of the droplet,

forming sealed graphene liquid pockets within 10 min. The sandwiched graphene liquid cell was loaded into a TEM for imaging within 30 min of its formation.

Kinetic Model for Monte Carlo simulations

Our model for nanocrystal etching resolves only the collection C of FCC lattice sites that are occupied by gold atoms at a given time. This list changes as a result of stochastic microscopic events whose rate constants we prescribe.

The dynamics of an atom detaching from the surface of a nanoparticle is shaped by many factors: the local surface structure, presence and arrangement of passivating ligand molecules, and the spatial distribution of oxidizing species, among others. We focus exclusively on the expectation that more highly coordinated atoms face higher energetic barriers to detachment, and are therefore etched less rapidly. Specifically, the removal rate k(n) of a particular surface atom is taken to depend only on the number n of its nearest-neighbor lattice sites that are occupied.

Many features of the resulting etching trajectories are insensitive to the precise form of k(n), requiring only that it declines sharply with n for highly coordinated sites. The particular form we choose follows from a simple kinetic description of the association between oxidizing species in solution and the nanoparticle surface: oxidants bind to a given surface atom with rate k_{on} ; upon binding, a surface atom (denoted Au) becomes activated for etching (denoted Au^*). The activated surface atom may either deactivate (through unbinding of the oxidant, which occurs with rate k_{off}) or detach from the nanoparticle with rate k_{detach} , as represented in the chemical equation:

$$Au \xrightarrow[]{k_{off}} Au^* \xrightarrow[]{k_{detach}} 0.$$
(1)

The resulting rate of detachment, $r = k_{detach}p(Au^*)$, thus depends on the probability $p(Au^*)$ that the atom is activated. The quantity $p(Au^*)$ is generally time-dependent; for simplicity, we employ a steady-state approximation $\frac{dp(Au^*)}{dt} \approx 0$, which leads to:

$$k_{on}p(Au) - \left(k_{off} + k_{detach}\right)p(Au^*) \approx 0, \tag{2}$$

yielding an effective rate constant for etching k = r/p(Au),

$$k = \frac{k_{on}}{1 + k_{off}/k_{detach}}.$$
(3)

Surface atoms that detach readily once activated (relative to the rate of oxidant unbinding) thus etch at essentially the same rate, i.e., etchant binding is the rate limiting step. Sites that detach slowly even when activated etch at much lower rates.

We take an Arrhenius form for detachment kinetics,

$$k_{detach} = k_0 e^{-\beta \epsilon n},\tag{4}$$

with an energetic barrier that grows linearly with coordination number n, where $\beta = 1/k_BT$. Assuming k_{off} to be independent of n, and defining parameters μ and n^* through:

$$e^{\beta\mu} = \frac{k_{off}}{k_0} \tag{5}$$

$$\mu = -n^* \epsilon, \tag{6}$$

we finally have:

$$k = \frac{k_{on}}{1 + e^{\beta \epsilon (n - n^*)}} \tag{7}$$

or equivalently,

$$k = \frac{k_{on}}{1 + e^{\beta(\epsilon n + \mu)}}.$$
(8)

We anticipate that reaction barriers are high, $\beta \epsilon \gg 1$, so that the Fermi function form of Eq. (7) implies:

$$k(n) \approx k_{on}, \qquad n < n^* \tag{9}$$

$$k(n) \approx k_{on} e^{-\beta \epsilon (n-n^*)} \ll k_{on}, \qquad n > n^*.$$
⁽¹⁰⁾

The second expression for the effective etching rate, Eq. (8), highlights an isomorphism between our kinetic model and Monte Carlo sampling of a classic statistical mechanics model for phase separation, namely the lattice gas (40).

We generated a collection of stochastic etching trajectories for several different values of n^* using the Gillespie algorithm for kinetic Monte Carlo sampling with the rates given in Eq. (7). We obtain essentially indistinguishable results using a discrete-time Monte Carlo scheme based on the aforementioned lattice gas analogy (an explicit comparison between these two methods for $n^* = 6.5$ is shown in fig. S35.) The latter approach offers significant practical advantages when the model is elaborated to describe surface diffusion. For this reason, most of the trajectories we report were generated with lattice gas Monte Carlo methods, which we detail below. (Except where noted, results presented in all figures were generated in this way.)

Lattice gas Monte Carlo

The dynamical variables of a lattice gas specify the presence ($\rho_i = 1$) or absence ($\rho_i = 0$) of material at each of a collection of lattice sites *i*. Their equilibrium fluctuations in a grand canonical ensemble are governed by a distribution of $C = \{\rho_1, \rho_2, ...\}$ given by:

$$P(C) \propto e^{-\beta H},\tag{11}$$

with the Hamiltonian:

$$H = -\mu \sum_{i} \rho_{i} - \epsilon \sum_{\langle i,j \rangle} \rho_{i} \rho_{j}, \qquad (12)$$

where μ is an externally imposed chemical potential. The second summation in *H* includes all distinct pairs of nearest neighbor lattice sites, which contribute an attractive energy – ϵ when both are occupied.

The simplest Monte Carlo scheme for sampling the distribution Eq. (11) would (i) select a lattice site *i* at random, (ii) attempt to change its occupation state $\rho_i \rightarrow 1 - \rho_i$, and (iii) accept the change with probability $A(C \rightarrow C')$, where *C* and *C'* are the states of the system before and after the proposed change. Any choice of *A* that satisfies detailed balance suffices for this purpose. The Glauber acceptance probability (41):

$$A(C \to C') = \frac{1}{1 + e^{\beta(H(C') - H(C))'}}$$
(13)

is a common choice, particularly when trajectories are given a dynamical interpretation (associating a small time interval with each MC step). If the configurational distribution changes smoothly in time, then this discrete-time scheme is equivalent to a continuous-time kinetics with transition rates:

$$k(\mathcal{C} \to \mathcal{C}') = w_0 A(\mathcal{C} \to \mathcal{C}'), \tag{14}$$

where w_0 is a constant with units of inverse time. In the particular case of a deletion move, which takes $\rho_i = 1$ to $\rho_i = 0$, this rate becomes:

$$k(\mathcal{C} \to \mathcal{C}') = \frac{w_0}{1 + e^{\beta(\epsilon n + \mu)'}}$$
(15)

where *n* is the coordination number of site *i* in configuration *C*. This rate corresponds precisely to the etching rate k(n) described in the previous section, establishing an equivalence between our kinetic model of nanocrystal etching and the deletion moves of a discrete-time grand canonical Glauber Monte Carlo sampling. In light of this equivalence, we interpret the chemical potential $\mu = -\epsilon n^*$ as a proxy for the driving force for etching. While it could be related in a complicated way to such underlying factors as etchant concentration and the electron beam strength, we treat it as an effective parameter that determines which coordination-number-dependent etching events are facile.

The precise lattice gas sampling scheme sketched above is not well-suited for etching trajectories, since only a small fraction of lattice sites are capable of changing in a given configuration (those at the nanocrystal surface). We therefore propose Monte Carlo moves that attempt only to modify the occupation state of changeable lattice sites. For deletion moves, the number of such changeable sites is $N_{surf}(C)$, i.e., the number of atoms that are incompletely coordinated. For insertion moves, the number of changeable sites is instead the number $N_{vac}(C)$ of vacancies that are adjacent to occupied sites (though in the strongly non-equilibrium etching regime, the probabilities of insertion moves are so small that these moves are insignificant.)

Our primary scheme for simulating the etching of a nanoparticle is thus as follows:

1. Determine whether to attempt deleting an atom or inserting an atom, with probability 1/2 for either move.

2. If attempting insertion, select one vacancy *j* at random from the $N_{vac}(C)$ vacancies associated with the configuration. Then, accept the "trial move" of changing the current configuration *C* into another configuration *C*' by changing $\rho_j = 0$ to $\rho_j = 1$ with probability:

$$A_{insert}(C \to C') = \frac{1}{1 + (f(C, C'))^{-1'}}$$
(16)

where:

$$f(C,C') = \frac{N_{vac}(C)}{N_{surf}(C')} e^{-\beta\Delta H},$$
(17)

$$\Delta H = H(C') - H(C) = -\mu - \varepsilon n.$$
(18)

The ratio of N's in the function f preserves detailed balance, and $\beta = 1/k_B T$ is the inverse temperature.

If attempting deletion, select one atom *j* at random from the $N_{surf}(C)$ atoms associated with the configuration. Then, accept the trial move $C \rightarrow C'$ by changing $\rho_j = 1$ to $\rho_j = 0$ with probability:

$$A_{delete}(C \to C') = \frac{1}{1 + (g(C, C'))^{-1'}}$$
(19)

where:

$$g(C,C') = \frac{N_{surf}(C)}{N_{vac}(C')} e^{-\beta \Delta H},$$
(20)

$$\Delta H = H(C') - H(C) = \mu + \varepsilon n.$$
⁽²¹⁾

The ratio of *N*'s in the function *g* preserves detailed balance.

3. Repeat until the nanoparticle has been fully etched - i.e., no atoms remain.

Choice of parameters

In all simulations, the temperature was set to $k_BT = k_B * 300K = 0.0259eV$, and the bond energy ε was set to 0.3275eV, one-twelfth the bulk sublimation energy of gold (42). THH intermediates were observed for a relatively wide range of chemical potentials, $-8 < \frac{\mu}{\varepsilon} < -6$. In the language of the kinetic model, this corresponds to etching rates for which $6 < n^* < 8$. At $\mu/\epsilon = -6$,¹ the FCC lattice gas exhibits coexistence between macroscopic high-density and lowdensity phases, so that the crystal surfaces can relax substantially on the time scale of growth or etching. We find that the equilibrium truncated octahedron emerges in etching simulations at a value of μ/ϵ slightly above coexistence, e.g. $\mu/\epsilon = -5.98$. For significantly larger values than this (around $\mu/\epsilon = -5.9$ and above), the shape evolution is instead dominated by growth of the

¹ For a general lattice, coexistence occurs at $\mu^* = -Z\epsilon/2$, where Z is the maximum number of nearest neighbors that a lattice site can have. For an FCC lattice, Z = 12, so $\mu^* = -6\epsilon$.

nanoparticle. Precisely at $\mu/\epsilon = -6$, any finite initial structure constitutes a sub-critical nucleus, which dissolves as a consequence of interfacial tension on time scales that hinder surface relaxation (43).

Surface relaxation

In the lattice gas scheme described above, the equilibrium truncated octahedron shape is obtained only when the rate of insertion of atoms is approximately equal to the rate of deletion of atoms, which occurs within a narrow range of chemical potential. By contrast, in experiments the equilibrium shape is observed under a wider range of driving forces. This indicates that the dominant mechanism of surface relaxation may not be insertion moves as controlled by a chemical potential, but rather surface diffusion mediated by the etchant. (In the absence of oxidizing conditions, surface diffusion on a nanoparticle is very slow) (44). We therefore also performed simulations where we attempted to relax nanoparticles via such diffusion moves.

We considered three different types of diffusion moves: "local" diffusion moves, where a surface atom can hop to a nearest-neighbor vacancy; "global" diffusion moves, where a surface atom can move to any unoccupied surface site on the nanoparticle; and an intermediate type of move, where a surface atom can hop to a nearest-neighbor vacancy or a *second* nearest-neighbor vacancy. We call this last type of move a "2-local" move.

To execute a local or global diffusion move, a surface atom is selected at random and a vacancy (chosen in a way appropriate to the type of diffusion that is being used) is also selected at random. (2-local moves are chosen in a somewhat different manner, which will be explained separately). These trial moves are then accepted with probabilities that preserve detailed balance; for local moves the probability is:

$$A_{local}(C \to C') = \frac{1}{1 + (d_l(C, C'))^{-1'}}$$
(22)

where:

$$d_l(C,C') = \frac{N_{surf}(C)n_{vac}(i)}{N_{surf}(C')n_{vac}(j)}e^{-\beta\Delta E},$$
(23)

$$\Delta E = E(C', j) - E(C, i) = -\epsilon_{diff} \Delta n.$$
(24)

Here, $n_{vac}(i)$ is the number of vacancies adjacent to atom *i* of configuration *C*, ϵ_{diff} is the energy barrier to diffusion, and Δn is the total change in the number of bonds in going from *C* to *C'*. The ratio of *N*'s and *n*'s in d_l is chosen so as to preserve detailed balance. For global moves, the probability is:

$$A_{global}(C \to C') = \frac{1}{1 + (d_g(C, C'))^{-1'}}$$
(25)

where:

$$d_g(C,C') = \frac{N_{surf}(C)N_{vac}(C)}{N_{surf}(C')N_{vac}(C')}e^{-\beta\Delta E},$$
(26)

$$\Delta E = E(C') - E(C) = -\epsilon_{diff} \Delta n.$$
(27)

Here Δn is again the total change in the number of bonds and the ratio of N's and n's in d_g is chosen so as to satisfy detailed balance.

For 2-local moves, surface atoms are still selected at random, but the vacancies are selected slightly differently. In particular, instead of selecting a single vacancy from a list of all eligible vacancies, one of the nearest neighbors of the selected atom is chosen at random (regardless of whether that neighbor is occupied or unoccupied), and then a neighbor of that site is chosen at random (again, regardless of whether that neighbor is occupied or unoccupied.) Then, this site is rejected if it is not a surface vacancy, i.e. a vacancy that is a nearest neighbor of a surface atom.² If the site *is* a surface vacancy, then the diffusion move is accepted with a probability:

$$A_{2-local}(C \to C') = \frac{1}{1 + (d_{2l}(C, C'))^{-1}},$$
(28)

where:

$$d_{2l}(C,C') = \frac{N_{surf}(C)}{N_{surf}(C')} e^{-\beta\Delta E},$$
(29)

$$\Delta E = E(C') - E(C) = -\epsilon_{diff} \Delta n.$$
(50)

Calculation of h-index from Monte Carlo simulations

We used simple geometry to calculate the h-index in our simulations. The "h" refers to the first index in the general zone-axis formula {hkl}, and represents (the inverse of) the slope of a series of receding {100} surfaces, i.e. the inverse of the slope of the pyramidal faces in our simulated THH nanoparticles. To compute *h*, the value of the h-index, consider the vectors \vec{v}_{100} and \vec{v}_{110} , which point from the center of a THH nanoparticle to the border of the nanoparticle in the [100] and [110] directions, respectively. Define the difference between these vectors as the *h*-vector:

$$\vec{v}_h = \vec{v}_{100} - \vec{v}_{110}$$

These vectors are shown in the figure below. With respect to a coordinate system with $v_{100} = \vec{v}_{100}/|\vec{v}_{100}|$ fixed, the slope of h-vector is given by:

$$m = \frac{\vec{v}_h \cdot \hat{v}_{100}}{\vec{v}_h \cdot (\mathbf{1} - \hat{v}_{100} \hat{v}_{100})}$$

Where 1 is the 3 × 3 unit matrix and $\vartheta_{100}\vartheta_{100}$ is the dyad formed from ϑ_{100} . The h-index is calculated as the inverse of the slope of the h-vector:

$$h = 1/m$$

In our calculations, for each configuration, the h-index is computed by averaging over the 24 possible h-indices of the THH (6 pyramids × 4 faces on each pyramid.)

(30)

² For a given atom in an FCC lattice, there are thus 12x12=144 ways to select a (1st- or 2nd- nearest neighbor) site. Many of these sites will not be surface vacancies, of course, and so a number of them will be rejected; we found this approach simpler than explicitly finding and listing all the 1st- and 2nd- nearest neighbor surface vacancies.



Fig. S1. TEM images of different gold nanorod (a-e) and silica-coated gold nanorod (f) samples. The average dimensions are: (a) $(46.5 \pm 3.4) \text{ nm} \times (15.1 \pm 1.0) \text{ nm}$, (b) $(75.0 \pm 3.5) \text{ nm} \times (25.2 \pm 1.9) \text{ nm}$, (c) $(84.1 \pm 4.8) \text{ nm} \times (17.6 \pm 1.5) \text{ nm}$, (d) $(90.1 \pm 4.0) \text{ nm} \times (24.2 \pm 1.7) \text{ nm}$, (e) $(140.5 \pm 7.4) \text{ nm} \times (32.0 \pm 2.0) \text{ nm}$, (f) $(78.0 \pm 4.8) \text{ nm} \times (23.5 \pm 1.0) \text{ nm}$. Silica shell thickness: $25.3 \pm 1.0 \text{ nm}$.



Fig. S2. TEM images of gold pentagonal bipyramid (a) and prism (b-d) samples. As shown in (b-d), the as-synthesized prism sample is composed of a mixture of hexagonal prisms, triangular prisms, icosahedra, and decahedra.



Fig. S3. TEM images of gold cubes (a,b), rhombic dodecahedra (c,d), and octahedra (e,f).



Fig. S4. Sequential images extracted from Movie S3. No etching was observed when a solution of gold nanorods dispersed in Tris buffer (pH=8.2) was encapsulated in a GLC without FeCl₃. The electron dose rate was 217 electrons/Å²·s.



Fig. S5. Sequential images extracted from Movie S3. No etching was observed when an acidic solution (acidified with HCl, pH=0.92) of gold nanorods dispersed in Tris buffer was encapsulated in a GLC without FeCl₃. The electron dose rate was 217 electrons/Å²·s.



Fig. S6. Sequential images extracted from Movie S3. No etching was observed when a solution of Au@SiO₂ nanorods dispersed in a mixture of Tris buffer and acidified FeCl₃ was encapsulated in a GLC (final [FeCl₃] =0.04 M, pH=0.92). The electron dose rate was 217 electrons/Å²·s.



Fig. S7. No etching was observed when a solution of Au nanorods dispersed in a mixture of Tris buffer, acidified FeCl₃, and isopropanol to quench oxidative species was encapsulated in a GLC (final [FeCl₃] =0.04 M, [isopropanol] =0.15M, pH=0.92). The electron dose rate was 86 electrons/Å²·s.



Fig. S8. Sequential images extracted from Movie S3. No etching was observed when a solution of Au nanorods dispersed in a mixture of Tris buffer, acidified FeCl₃ and isopropanol to quench oxidative species was encapsulated in a GLC (final [FeCl₃] =0.04 M, [isopropanol] =0.15M, pH=0.92). The electron dose rate was 254 electrons/Å²·s.



Fig. S9. Sequential images extracted from Movie S3. A negligible degree of etching was observed when a solution of Au nanorods dispersed in a mixture of Tris buffer and a lower concentration of acidified FeCl₃ was encapsulated in a GLC (final [FeCl₃] =0.02 M, pH=1.25). The electron dose rate was 217 electrons/Å²·s.



Fig. S10. Selected contours of rod etching reactions under fast kinetic (a, Movie S5) and slow equilibrium (b, Movie S1) conditions that have been scaled to better illustrate the change in *relative* particle shape. Contrast the appearance of an ellipsoidal intermediate in the non-equilibrium regime with the blunting and faceting observed in the equilibrium regime.



Fig. S11. Plots of dimensions versus time (a,c) and longitudinal dissolution rate versus tip curvature (b,d) for the rod (a,b) and blunted rod (c,d) shown in Figure 2. The electron dose rate was 217 electrons/Å²·s.



Fig. S12. Complete dataset of time-domain contour plots for the rod (a) and blunted rod (b) reactions shown in Figure 2. Contour lines are spaced in time by 0.4 seconds.



Fig. S13. Time-domain contour plots and selected time-lapse TEM images of additional oxidative dissolution reactions for gold rod (a,b) and blunted rod (c,d) nanocrystals extracted from Movies S2 (a,b) and S9 (c,d), respectively. Contour lines are spaced in time by 0.8 and 1.2 seconds in (a) and (c), respectively. The electron dose rate was 217 electrons/Å²·s.

Fig. S14. Schematic illustrating how curvature-selective etching can result in sharper-tipped nanocrystal intermediates. Because the tips of nanorods (red hemispheres) are curved along two orthogonal dimensions but the sides of nanorods (blue cylinders) are curved along one dimension, a lower areal density of surface ligands is expected at the tips than the sides. This results in more rapid removal of material at the tips relative to the sides, generating an ellipsoidal geometry. For example, when schematic nanorod tips (red) are reduced by 10% while the sides (blue) are reduced by 5% over several steps (left to right sequence of images), a sharper-tipped ellipsoidal nanocrystal intermediate is generated. Presumably, under normal solution conditions, surface relaxation would equilibrate these high-energy features, resulting in the shortened but still rod-shaped nanocrystals that have been frequently observed in *ex situ* experiments. The sustained non-equilibrium conditions in the liquid cell allow observation of the ellipsoidal intermediate by ensuring that the rate of atom removal is faster than the rate of surface relaxation.



Fig. S15. Comparison of rod etching simulations under near-equilibrium (left, $\frac{\mu}{\epsilon} = -5.98$) and non-equilibrium (right, $\frac{\mu}{\epsilon} = -6.5$) conditions (Movie S6). For the near-equilibrium rod etching, the number of attempted steps was 5.00×10^7 and the acceptance ratio was ~ 0.0317 . For the non-equilibrium rod etching, the number of attempted steps was $\sim 3.00 \times 10^7$ and the acceptance ratio was ~ 0.0677 . Images are viewed along the $\langle 100 \rangle$ zone axis. Whereas the experimental faceting of the rod under near-equilibrium conditions (figs. S10 and S16, Movie S1) is observed in the simulation (left), the experimental tip-selective etching and transformation to an ellipsoidal intermediate (fig. S10, S12 and S13, Movie S2) is not observed in the simulation (right). This implies that the effects of decreased areal ligand density around the nanorod tips (which are not considered in the simulation) are responsible for the experimental observations. As mentioned in the main text, this interpretation is consistent with numerous reports from the literature (24, 45).



Fig. S16. Time-domain contour plot (a) and selected time-lapse TEM images (b) for the equilibrium rod dissolution reaction shown in Figure 1 extracted from Movie S1. Note the initial appearance of sharp features (top set of arrows) which eventually develop into lower-energy blunt facets (bottom set of arrows, see Movie S7 for further illustration). Contour lines are spaced in time by 3.6 seconds. The electron dose rate was 217 electrons/Å²·s.



Fig. S17. (a) Normalized length versus time for several different nanocrystal shapes extracted from Movies S15 (triangular prism), S10 (pentagonal bipyramid), S5 (rod), S43 (cube), and S9 (blunted rod). (b) Quantification of the initial etching rate as a function of initial tip curvature for differently-sized rods and bipyramids (black), and for a cube (red square) and a triangular prism (red triangle). Note the deviation from the linear trend for the particles with curvature along only one dimension (red data points) compared to those with curvature along two orthogonal dimensions (black data points).



Fig. S18. Characterization of additional oxidation reactions for pseudo-one-dimensional nanocrystals: pentagonal bipyramid (a-c) and a rod/blunted rod pair (d-f). Selected time-lapse TEM images extracted from Movies S10 (a) and S16 (d), plots of longitudinal dissolution rate and tip curvature as a function of time (b,e), and time-domain contour plots (c,f). Vertical dotted lines in (b, e) correspond to the time-labeled contours in (c, f). Contour lines are spaced in time by 0.4, 1.2, and 0.8 seconds for bipyramid (c), blunted rod (f) and rod (f), respectively.



Fig. S19. Initially cubic, ~7 million-atom nanoparticles etched, with both insertion and deletion moves allowed, at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon}$ = -5.98, -6.0, -6.25, -6.75, -7.0, -8.0 (Movie S24). Low values of the chemical potential show equilibrium or near-equilibrium structures while higher values show the formation of the THH. Images are viewed down the $\langle 100 \rangle$ zone axis.



Fig. S20. Time-domain contour plot (a) and selected time-lapse TEM images (b) for an equilibrium cube dissolution reaction conducted at reduced etchant concentration extracted from Movie S21. Note the initial appearance of sharp features (top set of arrows) which eventually develop into lower-energy blunt facets (bottom set of arrows, see Movie S22 for further illustration). Contour lines are spaced in time by 3.2 seconds. The electron dose rate was 86 electrons/Å²·s.



Fig. S21. TEM images of ex-situ ensemble etching of gold cubes into truncated octahedra. Cubes were dissolved in 1.5 mL of 50 mM CTAB solution (OD = 3), to which 5 μ L of 10 mM HAuCl4 was added. The reaction was allowed to proceed for one hour at room temperature under 500 rpm stirring.

Fig. S22. Surface diffusion of an initially cubic nanoparticle with ~130,00 atoms (Movie S23). From left to right: local diffusion, 2-local diffusion, global diffusion. Each case allows the system to relax to the equilibrium shape (truncated octahedron), albeit at different rates. Here, no etching (insertion or deletion moves) are allowed, and only diffusion moves occur.

Fig. S23. Complete dataset of time-domain contour plots for the cube (a) and rhombic dodecahedron (b) reactions shown in Figure 3. Contour lines are spaced in time by 0.4 seconds.

Fig. S24. Time-domain contour plots and selected time-lapse TEM images of additional oxidative dissolution reactions for gold cube (a,b) and rhombic dodecahedron (c,d) nanocrystals extracted from Movies S18 and S28, respectively. Contour lines are spaced in time by 0.4 and 0.8 seconds in (a) and (c), respectively.

Fig. S25. Comparison of contour plots extracted from experimental (a,c) and simulation (b,d) movies for cube (a,b) and rhombic dodecahedron (c,d) nanocrystal oxidation reactions extracted from Movies S17, S19, S27, and S29 for (a), (b), (c), and (d), respectively.

Fig. S26. Ratio of crystallographic dissolution rates for cube (a) and rhombic dodecahedron (b) etching reactions presented in Figure 3. Schematic illustrations of the relevant crystallographic orientation are shown at right.

Fig. S27. Idealized etching of a cube in which atoms with coordination number ≤ 6 are deterministically removed at each step. Several crystallographic perspectives are shown. Legend at bottom denotes the color value applied to atoms with different coordination numbers. Note the appearance and recession of {100} terraces via the removal of edge and corner atoms to create vicinal {210} facets. See also Movie S26.

Fig. S28. Initially rhombic-dodecahedral, ~6 million-atom nanoparticles etched, with both insertion and deletion moves allowed, at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon} = -5.98$, -6.0, -6.25, -6.75, -7.0, -8.0 (Movie S31). Images are viewed down the $\langle 100 \rangle$ zone axis.

Fig. S29. Time-domain contour plots and selected time-lapse TEM images of the oxidative dissolution of gold triangular prisms extracted from Movies S36 (a,b,), S38 (c,d) and S39 (e,f). At lower FeCl₃ concentrations, reactions are slow and the particle develops low-energy facets (a,b, see also Movie S37). At higher FeCl₃ concentrations, reactions are driven out of equilibrium and unusual intermediate shapes with 7 and 5 side facets are observed (c-f). Contour lines are spaced in time by 1.2 seconds in (a) and 0.8 seconds in (d) and (e). The electron dose rate was 217 and 86 electrons/Å²·s for (a,b) and (c-f), respectively.

Supplementary Text

Discussion of nanoparticle products formed under equilibrium and non-equilibrium etching conditions

A perfect cubic nanocrystal consisting of an FCC material bound by {100} facets will have edges with coordination number (n) equal to 5 and corners with n = 3 (step 0, fig. S27). In the equilibrium regime, atoms with n = 6 will fluctuate and atoms with n < 6 will etch. Therefore, the initial cube configuration will quickly experience etching of the tips and edges, revealing step edges with atoms that have n = 6 (step 1, fig. S27). The surface of the nanoparticle then proceeds to relax, reorganizing so as to minimize the total free energy. As dictated by the Wulff construction (46), the resulting surface-energy-minimizing shape is a truncated octahedron. This equilibrium shape transformation is observed in both experiment (fig. S20 and S22, Movies S21-S22) and simulation (figs. S19 and S21, Movies S23-S25). Capturing this shape change in simulations takes two forms. In the first, following the scheme outlined in the "Lattice gas Monte Carlo" section of S1, both insertion and deletion moves are allowed but the truncated octahedron is only observed within a narrow range of values of the chemical potential. In the second, diffusion-like MC moves that foster relaxation by transporting surface atoms to other sites on the nanoparticle surface, in a way that satisfies detailed balance, are introduced. However, the equilibrium shape is attained only when diffusion rates are much higher than those on an unperturbed nanocrystal. We thus propose that oxidative etching, in addition to removing material from a nanoparticle, renders its surface significantly more labile.

In the non-equilibrium case, the rate at which atoms with n = 6 are etched is made much greater than the rate at which atoms with n = 7 and higher are etched. In the language of the lattice gas model, the chemical potential is set such that deletion of surface atoms with n = 6 is facile, whereas insertion of such atoms is not. As a result, after the initial edge (n = 5) and tip (n = 3)atoms are removed and the step edges (n = 6) are revealed (step 1, fig. S27), the system continues to experience etching rather than being allowed to equilibrate to the minimum-energy Wulff shape. As the first n = 6 edges withdraw, new step edges are revealed which also have n = 6. This results in persistent recession of $\{100\}$ terraces whose periphery are always defined by n = 6 atoms. Eventually, a step train is formed: a vicinal surface with equidistant steps (steps 7-19, fig. S27) (32). This process is the etching equivalent of the well-known step-flow crystal growth mechanism first described by Burton, Cabrera, and Frank in 1951 and is referred to as step recession (29-31). Since step recession occurs with equal velocity from all four sides of the initial {100} facets, receding edges will eventually meet in the center of the original cube face. The resulting feature that remains will be a square pyramid whose angle with respect to the {100} plane will be defined by the ratio of step height to terrace width in the step train. This is equivalent to describing the facets as vicinal $\{hk0\}$ where h>k and the ratio h/k is related to the angle of the pyramidal feature. The shape that results when these pyramidal features form on each of the six faces of the original cube is a tetrahexahedron (THH, Movie S26). Because the chemical potential will continually generate edges with n = 6 via step recession, a non-equilibrium condition is achieved in which the THH shape is transiently stable so long as the rate of etching is considerably faster than the rate at which the system can relax (see below).

Fig. S30. Stereographic triangle connecting the low-index poles of an FCC metal with their nanocrystal representations of cube $\{100\}$, rhombic dodecahedron $\{110\}$, and octahedron $\{111\}$ particles. Cube and rhombic dodecahedron particles are connected by a series of $\{hk0\}$ -bound particles, all of which represent tetrahexahedra with different pyramidal angles (θ , see Fig. 4B, inset).

The stereographic projection is a useful tool for illustrating the connection between different crystallographic surface facets by representing all {hkl} planes as points (also called poles) on a two-dimensional surface that preserves the angular relationship between them. Paths connecting two points represent possible transitions between planes that proceed through numerous gradual changes in miller indices and surface energy. If instead of viewing these pathways as transitions between atomic planes they are imagined as transitions between nanocrystals bound in these {hkl} surface facets, potential shape transformation reactions can be generated (47-49). When applied to a system with cubic symmetry, it can be seen that {100}-bound cube and {110}-bound rhombic dodecahedron nanocrystals can both transform into particles bound by {hk0} facets through relatively small movements in stereographic space (i.e., small changes in the crystallographic angles of their faces, fig. S30). As mentioned above, any {hk0}-bound single crystalline shape (where $h>k\geq1$) will be a tetrahexahedron where the angle of the pyramidal feature with respect to the {100} facet (θ) is defined by:

$$\theta = \cos^{-1}\left(\frac{h}{\sqrt{h^2 + k^2}}\right)$$

Therefore, although the cube and rhombic dodecahedron nanocrystal both transition to {210} THH intermediates in simulations, they do so from opposite poles in the stereographic projection and, as a result, necessarily follow distinct pathways (fig. S30). While the cube will approach the {210} THH ($\theta = 26.6$) by transitioning through several other THH particles defined by {h10} vicinal facets ($\theta < 26.6$), the rhombic dodecahedron ($\theta = 45$) will instead access the {210} through THH particles defined by non-vicinal facets ($\theta > 26.6$). This explains the observation in simulations of a

{310} THH as one of the intermediate products of the cube etching reaction but not in the rhombic dodecahedron etching reaction.

Interestingly, for both the cube and the rhombic dodecahedron etching reactions, simulations predict the far-from-equilibrium product to be a {210} THH while the measured experimental structure is a {310} THH (Fig. 3 and 4). As mentioned in the main text, this discrepancy likely arises from factors which are not accounted for in the simulations. One intriguing possibility involves the role of the CTAB ligands in directing the stability of different vicinal surfaces. Several groups have reported evidence of selective binding of CTAB to {100} compared to other low-index facets in FCC metal nanocrystals (*50-52*). Since the {310} facet has a larger {100} terrace area compared to the {210} (Fig. 4, C and D), CTAB ligands may be able to more effectively bind and stabilize these facets. Therefore, although the appearance of {310} THH intermediates is mostly driven by non-equilibrium coordination number-based processes (see above), a competing effect that favors more open vicinal facets may be driven by ligand binding. The nuances of these ligand effects will be the subject of future investigations.

Effect of varying parameters

To test the robustness of our Monte Carlo model, we investigated the behavior of the system for different particle sizes and different values of the chemical potential. Simulations conducted with three different nanoparticle sizes (1 million, 7 million, and 55 million atoms) etching at $\mu/\epsilon =$ -6.5 are shown below (figs. S31-S32). In each case, it is clear that regardless of the size, the limiting shape under non-equilibrium conditions is a THH.

Fig. S31. Left to right: nanoparticles which were initially cubic, with sizes of ~1, 7, and 55 million atoms, all etched to THH configurations at $\frac{\mu}{\epsilon} = -6.5$ (Movie S40). Images are viewed down the $\langle 100 \rangle$ zone axis.

Fig. S32. Left to right: nanoparticles which were initially rhombic dodecahedra, with sizes of ~1, 6, and 50 million atoms, all etched to THH configurations at $\frac{\mu}{\epsilon} = -6.5$ (Movies S41-S42). Images are viewed down the $\langle 100 \rangle$ zone axis.

To probe the effect of chemical potential on non-equilibrium shape transformation, simulations were conducted at a number of different values of μ/ϵ (figs. S19 and S28, and Movies S24-S25, S31-S34). It appears that since the THH intermediate is generated over a range of different values of the chemical potential, the THH is a rather general non-equilibrium configuration for etching of an FCC lattice. It was observed experimentally that for very high dose rates (effective driving force), the intermediate structure stays cubic or nearly cubic for the entire reaction (fig. S33, Movie S43). This is precisely what is observed upon increasing the chemical potential to $\mu/\epsilon = -8$ in the Glauber dynamics simulations (fig. S19, Movie S24).

Fig. S33. Time-domain contour plot and selected time-lapse TEM images of a cube etching reaction extracted from Movie S43. The higher driving force (electron dose rate of 217 electrons/Å²·s) suppresses the observation of the THH intermediate, as predicted by simulations (see fig. S19 and Movie S24). Contour lines are spaced in time by 0.8 seconds.

We also note that we can induce nanoparticle growth by increasing the chemical potential to values significantly greater than $\frac{\mu}{\epsilon} = -6.0$ (fig. S34).

Fig. S34. Growth of an initially cubic nanoparticle of size ~7 million atoms via nucleation on the {100} surfaces for the case of $\frac{\mu}{\epsilon} = -5.0$ (Movie S24).

Note that when the system is precisely at coexistence $(\frac{\mu}{\epsilon} = -6.0)$ the nanoparticle etches to a seemingly featureless, spherical shape, and continues etching, gradually, until it disappears completely (Movies S24-S25, S31-S34). As discussed in S1, though, the instability of finite (non-macroscopic) phases at coexistence is actually predicted by classical nucleation theory (43). Therefore, to observe the equilibrium structure, we must use a chemical potential slightly above coexistence – hence our choice of $\frac{\mu}{\epsilon} = -5.98$ for the equilibrium etching simulation.

Effect of diffusion

As discussed in section S1, we expect that some type of etchant-mediated diffusion, rather than the insertion moves of the lattice gas model, is a plausible mechanism for nanoparticle surface relaxation. To obtain a better sense of the nature of this diffusion process, we subjected simulated nanoparticles to several types of diffusion, described in section S1. Snapshots of an initial cubic nanocrystal containing ~130,000 atoms subjected to these different types of diffusion, with no etching moves allowed are shown in fig. S22. Here, we chose $\epsilon_{diff} = \epsilon/5$, to make the barrier to diffusion lower than the energetic barrier to etching (presumably diffusion is a less violent bondbreaking process than etching) and hence the diffusion rate higher. All the simulations show that the nanoparticles are heading towards a truncated octahedron shape - the corners disappear and form {111} facets while the side {100} faces shrink in area but grow additional layers. However, for the same number of attempted diffusion moves (1×10^9) , global diffusion approximates the equilibrium truncated octahedron shape much more closely than either local or 2-local diffusion. It is apparently much easier, and takes fewer MC steps, to attain the equilibrium shape using global diffusion than using either local or 2-local diffusion.

We also performed simulations where both etching and surface diffusion moves were allowed. Here, we examined ~7 million-atom nanoparticles, with the chemical potential set to $\mu/\epsilon = -6.5$. We attempted global diffusion moves with a probability *R* for values R = 0.9, 0.99, 0.999. (For values much less than 0.9, the presence of diffusion moves had essentially

no effect on the shape evolution.) Deletion moves and insertion moves were both attempted with probability (1 - R)/2 though insertion moves were accepted at a rate so small as to be negligible (fig. S35). As can be seen, for sufficiently large *R*, surface diffusion dominates etching, resulting in the attainment of the equilibrium, truncated octahedron shape.

Fig. S35. Left to right: ~7-million-atom nanoparticles which were initially cubic, subjected to a combination of global diffusion and etching moves, with diffusion attempt probabilities R = 0.9, 0.99, and 0.999. The ratios of accepted diffusion moves to etching moves were ≈ 2 , 21, and 260, respectively. Etching was done at $\frac{\mu}{\epsilon} = -6.5$. Images are viewed along the $\langle 100 \rangle$ zone axis.

Effect of Monte Carlo Dynamics

A number of different Monte Carlo algorithms have been used to simulate nanocrystal systems. Here we compare Glauber dynamics (implemented for the majority of the data presented here) to Metropolis dynamics (53) and to the kinetic Glauber scheme described in S1. Metropolis dynamics is implemented in a way nearly identical to Glauber dynamics; for Metropolis dynamics, though, the acceptance probabilities are given by:

$$\begin{aligned} A_{insert}(C \to C') &= \min\left[1, \frac{N_{vac}(C)}{N_{surf}(C')}e^{-\beta\Delta H}\right], \\ A_{delete}(C \to C') &= \min\left[1, \frac{N_{surf}(C)}{N_{vac}(C')}e^{-\beta\Delta H}\right], \\ \Delta H &= H(C') - H(C). \end{aligned}$$

Fig. S36. Comparison of etching structures generated with three different types of dynamics (Glauber, Metropolis, and kinetic Glauber).) Each nanoparticle image represents a configuration where $V/V_{init} \approx 0.3$. For the Metropolis dynamics, the number of attempted steps was $\sim 1.34 \times 10^8$ and the acceptance ratio was ~ 0.0526 and for the Glauber dynamics the number of attempted steps was $\sim 1.34 \times 10^8$ and the acceptance ratio was ~ 0.0524 .

When the chemical potential is set to $\mu/\epsilon = -6.5$ (for the Glauber and Metropolis dynamics), the etching structures that result from the three types of algorithms appear nearly identical and are indeed THH shapes; quantification of the h-index over time shows that they are statistically indistinguishable (fig. S36). The appearance of a THH during etching thus appears to be robust to the specific choice of dynamics.

Sensitivity of Etching to FeCl3 Concentration

Because $k_B T$ is small compared to the bond energy, the acceptance probability functions for insertion or deletion of atoms have a very sharp slope centered around the value of the chemical potential. In our "nonequilibrium" regime ($\mu/\epsilon = -6.5$), the probability of deleting any surface atom with 6 or fewer nearest neighbors is essentially 1, and the probability of inserting an atom which will have 6 or fewer nearest neighbors is essentially 0. At our "near-equilibrium" value of the chemical potential, $\mu/\varepsilon = -5.98$, these probabilities are roughly equal. This narrow distribution about the chemical potential provides a possible explanation as to why small changes (e.g. a factor of 2) in the etchant concentration can shift the behavior of the system from equilibrium to non-equilibrium. However, the importance of including mechanisms for surface diffusion in the simulations in order to observe near-equilibrium morphologies suggests that other factors may play an equal or greater role. The binding of FeCl₃ or its CTAB complexes to different nanocrystal facets may be responsible for modifying the surface diffusion coefficients and step motion parameters involved in the removal of Au atoms from a nanocrystal. Indeed, in the biomineralization literature, the inclusion of surface-binding additives has been shown to alter the morphology of inorganic crystals that grow via step-flow mechanisms (54). Ultimately, a complex network of bulk and surface reactions govern nanocrystal oxidation within the liquid cell that act in concert to create conditions in which small changes in the etchant concentration produce large changes in the nanocrystal morphology.

Movie ID	Content Description	Concentration of FeCl ₃ (mol/L)	Electron dose rate (electrons/Å ² •s)	Acquisition frame rate (s/frame)
S1	Figure 1: Equilibrium nanorod etching	0.02	217	0.4
S2	Figure 1: Non-equilibrium nanorod etching	0.03	217	0.2
S3	Nanoparticle etching control experiments	0-0.04	86-254	0.2, 0.4
S4	Additional equilibrium nanorod etching	0.02	1500	0.025
S5	Figure 2: Nanorod	0.04	217	0.4
S7	Progression of contours for equilibrium nanorod etching shown in Movie S1	0.02	217	0.4
S8	Figure 2: Blunted rod	0.04	217	0.4
S9	Additional blunted rod	0.03	217	0.4
S10	Pentagonal bipyramid	0.04	217	0.2
S11	Tip-selective blunting: Decahedron	0.03	86	0.4
S12	Tip-selective blunting: Rhombic dodecahedron	0.03	86	0.4
S13	Tip-selective blunting: Triangular bipyramid	0.04	86	0.2
S14	Tip-selective blunting: Octahedron	0.03	86	0.4
S15	Triangular prism	0.04	217	0.4
S16	Pair of regular and blunted nanorod	0.04	217	0.4
S17	Figure 3: Cube	0.04	86	0.4
S18	Additional cube	0.04	86	0.4
S21	Equilibrium etching of cube to truncated octahedron	0.02	86	0.4
S22	Progression of contours for equilibrium cube etching shown in Movie S21	0.02	86	0.4
S27	Figure 3: Rhombic dodecahedron	0.04	86	0.4
S28	Additional rhombic dodecahedron	0.04	86	0.4
S35	Pair of rhombic dodecahedron and cube	0.04	86	0.4
S36	Equilibrium etching and re-faceting of a triangular prism	0.02	217	0.4
S37	Progression of contours for equilibrium triangular prism etching shown in Movie S36	0.02	217	0.4
S38	Triangular prism with faceted intermediate	0.04	86	0.4
S39	Additional triangular prism with faceted intermediate	0.04	86	0.2
S43	Cube etched with higher dose rate	0.04	217	0.4

Table S1. Summary of TEM movies and their acquisition parameters.

Movie ID	Content Description	System Size (# atoms)	Chemical Potential (μ/ε)
S6	Rod etching viewed along the $\langle 100 \rangle$ zone axis	2 million	-5.98, -6.5
S19	Cube etching viewed along the $\langle 100 \rangle$ zone axis	7 million	-6.5
S20	Cube etching (color-coded with <i>n</i>) viewed along the $\langle 100 \rangle$ zone axis	7 million	-6.5
S23	Cube: Effects of surface diffusion viewed along the $\langle 100 \rangle$ zone axis	1.3 million	NA
S24	Cube etching viewed along the $\langle 100 \rangle$ zone axis	7 million	-5.0 to -8.0
S25	Cube etching (color-coded with <i>n</i>) viewed along the $\langle 100 \rangle$ zone axis	7 million	-5.0 to -8.0
S26	Cube: idealized etching	NA	NA
S29	Rhombic dodecahedron etching viewed along (110) zone axis	7 million	-6.5
S30	Rhombic dodecahedron etching (color-coded with <i>n</i>) viewed along $\langle 110 \rangle$ zone axis	7 million	-6.5
S31	Rhombic dodecahedron etching viewed along $\langle 100 \rangle$ zone axis	7 million	-5.0 to -8.0
S32	Rhombic dodecahedron etching viewed along $\langle 110 \rangle$ zone axis	7 million	-5.0 to -8.0
S33	Rhombic dodecahedron etching (color-coded with <i>n</i>) viewed along $\langle 100 \rangle$ zone axis	7 million	-5.0 to -8.0
S34	Rhombic dodecahedron etching (color-coded with <i>n</i>) viewed along $\langle 110 \rangle$ zone axis	7 million	-5.0 to -8.0
S40	Cube etching viewed along the $\langle 100 \rangle$ zone axis	1, 7 and 55 million	-6.5
S41	Rhombic dodecahedron etching viewed along $\langle 100 \rangle$ zone axis	1, 7 and 55 million	-6.5
S42	Rhombic dodecahedron etching viewed along $\langle 110\rangle$ zone axis	1, 7 and 55 million	-6.5

Table S2. Summary of Monte Carlo Simulation Movies and their parameters.

Movie S1. TEM movie of partial dissolution of a gold nanorod followed by tip re-faceting and development of {100} planes. The concentration of FeCl₃ was 0.02 M in the GLC loading solution. The acquisition frame rate is 2.5 fps. Two movies were recorded back-to-back with a dead time of 6 seconds between them, and were concatenated into a single movie. The electron dose rate was 217 electrons/Å²·s.

Movie S2. TEM movie of dissolution of a regular gold nanorod (89.1 nm x 27.4 nm). The acquisition frame rate is 5.0 fps. The electron dose rate was 217 electrons/Å²·s. The concentration of FeCl₃ was 0.03 M in the GLC loading solution.

Movie S3. A compilation video showing a series of control experiments *investigating the chemical conditions necessary to observe nanorod etching*. (From left to right, top to bottom):

TEM movie of dissolution of a regular gold nanorod (89.1 nm x 27.4 nm). The acquisition frame rate is 5.0 fps. The electron dose rate was 217 electrons/Å²·s. The concentration of FeCl₃ was 0.03 M in the GLC loading solution.

TEM movie of a gold nanorod dispersed in Tris buffer only (pH=8.2). No etching was observed under prolonged electron-beam illumination (~60 seconds). The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

TEM movie of a gold nanorod dispersed in an acidified Tris buffer solution (pH=0.92) without FeCl₃. No etching was observed under prolonged electron-beam illumination (~60 seconds). The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

TEM movie of a Au@SiO₂ core-shell nanorod dispersed in a mixture of Tris buffer and acidified FeCl₃ solutions (final [FeCl₃] =0.04 M, pH=0.92). No etching was observed under prolonged electron-beam illumination (~90 seconds). The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

TEM movie of a gold nanorod dispersed in a mixture of Tris buffer, acidified FeCl₃ and isopropanol (final [FeCl₃] =0.04 M, [isopropanol] =0.15M, pH=0.92). No etching was observed under prolonged electron-beam illumination (~55 seconds). The acquisition frame rate is 2.5 fps. The electron dose rate was 254 electrons/Å²·s.

TEM movie of a gold nanorod dispersed in a mixture of Tris buffer, acidified FeCl₃ and isopropanol (final [FeCl₃] =0.02 M, pH=0.92). A negligible degree of etching was observed after prolonged electron-beam illumination (~60 seconds). The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

Movie S4. High-resolution TEM movie of partial dissolution of a gold nanorod followed by tip re-faceting and development of {100} planes. The concentration of FeCl₃ was 0.02 M in the GLC loading solution. The acquisition frame rate is 400 fps. The original full field of view was binned by 4 before movie extraction. The electron dose rate was about 1500 electrons/Å²·s. This movie was acquired with the 300 kV aberration-corrected TEAM I microscope at the National Center for Electron Microscopy facility within The Molecular Foundry at Lawrence Berkeley National Laboratory.

Movie S5. TEM movie of dissolution of a regular gold nanorod (84.3 nm x 23.2 nm). The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

Movie S6. Monte Carlo simulation movie of a 2-million-atom nanorod etched at the chemical potential $\frac{\mu}{\epsilon} = -5.98$ and -6.5. For the near-equilibrium rod etching at $\frac{\mu}{\epsilon} = -5.98$, the number of attempted steps was 5.00×10^7 and the acceptance ratio was ~ 0.0317 . For the non-equilibrium rod etching at $\frac{\mu}{\epsilon} = -6.5$, the number of attempted steps was $\sim 3.00 \times 10^7$ and the acceptance ratios was ~ 0.0677 . Images are viewed along the $\langle 100 \rangle$ zone axis.

Movie S7. Contour plot movie showing the progression of nanocrystal local curvature for the equilibrium rod dissolution reaction shown in Figure 1 and Movie S1. Five contours are shown at any given time to better illustrate the development of low-energy blunt facets.

Movie S8. TEM movie of dissolution of a blunted gold nanorod. The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/ $Å^2 \cdot s$.

Movie S9. TEM movie of dissolution of an additional blunted gold nanorod. The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s. The concentration of FeCl₃ was 0.03 M in the GLC loading solution.

Movie S10. TEM movie of dissolution of a gold pentagonal bipyramid. The acquisition frame rate is 5.0 fps. The electron dose rate was 217 electrons/Å²·s.

Movie S11. TEM movie of partial dissolution of a gold decahedron that exhibits tip-selective blunting. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/Å²·s. The concentration of FeCl₃ was 0.03 M in the GLC loading solution.

Movie S12. TEM movie of partial dissolution of a gold rhombic dodecahedron that exhibits tipselective blunting. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/Å²·s. The concentration of FeCl₃ was 0.03 M in the GLC loading solution.

Movie S13. TEM movie of dissolution of a gold triangular bipyramid, found as an impurity shape in the gold octahedron synthesis, that exhibits tip-selective blunting. The acquisition frame rate is 5.0 fps. The electron dose rate was 86 electrons/Å²·s.

Movie S14. TEM movie of partial dissolution of a gold octahedron that exhibits tip-selective blunting. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/Å²·s. The concentration of FeCl₃ was 0.03 M in the GLC loading solution.

Movie S15. TEM movie of dissolution of a gold triangular prism. The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

Movie S16. TEM movie of simultaneous dissolution of a regular and blunted gold nanorod. The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/ $Å^2 \cdot s$.

Movie S17. TEM movie of dissolution of a gold cube exhibiting the tetrahexahedron transient intermediate shape. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/ $Å^2$ ·s.

Movie S18. TEM movie of dissolution of an additional gold cube exhibiting the tetrahexahedron transient intermediate shape. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/ $Å^2 \cdot s$.

Movie S19. Monte Carlo simulation movie of a cubic, 7-million-atom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon}$ = -6.5. The number of attempted Monte Carlo steps was ~1.34 × 10⁸, and the acceptance ratio was ~0.0524. The nanocrystal is viewed along the (100) zone axis.

Movie S20. Monte Carlo simulation movie of a cubic, 7-million-atom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon} = -6.5$. The number of attempted Monte Carlo steps was $\sim 1.34 \times 10^8$, and the acceptance ratio was ~ 0.0524 . The nanocrystal is viewed along the $\langle 100 \rangle$ zone axis and the atoms are color-coded according to their coordination numbers.

Movie S21. TEM movie of equilibrium etching of a gold cube. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/ $Å^2 \cdot s$. The concentration of FeCl₃ was 0.02 M in the GLC loading solution.

Movie S22. Contour plot movie showing the progression of nanocrystal local curvature for the equilibrium cube dissolution reaction shown in Movie S22. Five contours are shown at any given time to better illustrate the development of low-energy blunt facets.

Movie S23. Monte Carlo simulation movie of atomic surface diffusion of a cubic, 1.3-millionatom nanocrystal. The number of attempted moves for local, 2-local, and global was 2×10^9 , and the acceptance ratios were ~ 6.82×10^{-3} , 2.71×10^{-3} , and 6.50×10^{-3} , respectively. For "2-local long", 2×10^{10} steps were attempted instead. The nanocrystal is viewed along the $\langle 100 \rangle$ zone axis.

Movie S24. Monte Carlo simulation movies of a cubic, 7-million-atom nanocrystal etched at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon} = -5.0$, -5.98, -6.0, -6.25, -6.5, -6.75, -7.0, -8.0. The numbers of attempted Monte Carlo steps were: $\sim 1 \times 10^9$, 2×10^{10} , 2.49×10^9 , 1.44×10^8 , 1.34×10^8 , 1.29×10^8 , 8.14×10^7 , 3.84×10^7 , respectively, and the corresponding acceptance ratios were: $\sim 1.18 \times 10^{-2}$, 1.32×10^{-2} , 3.51×10^{-2} , 5.26×10^{-2} , 5.24×10^{-2} , 5.68×10^{-2} , 9.86×10^{-2} , 0.189. The nanocrystals are viewed along the $\langle 100 \rangle$ zone axis.

Movie S25. Monte Carlo simulation movies of a cubic, 7-million-atom nanocrystal etched at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon} = -5.0$, -5.98, -6.0, -6.25, -6.5, -6.75, -7.0, -8.0. The numbers of attempted Monte Carlo steps were: $\sim 1 \times 10^9$, 2×10^{10} , 2.49×10^9 , 1.44×10^8 , 1.34×10^8 , 1.29×10^8 , 8.14×10^7 , 3.84×10^7 , respectively, and the corresponding acceptance ratios were: $\sim 1.18 \times 10^{-2}$, 1.32×10^{-2} , 3.51×10^{-2} , 5.26×10^{-2} , 5.24×10^{-2} , 5.68×10^{-2} , 9.86×10^{-2} , 0.189. The nanocrystals are viewed along the $\langle 100 \rangle$ zone axis and the atoms are color-coded according to their coordination numbers.

Movie S26. Movie of the idealized etching of a cubic nanocrystal where atoms with coordination number ≤ 6 are deterministically removed at each step.

Movie S27. TEM movie of dissolution of a gold rhombic dodecahedron exhibiting the tetrahexahedron transient intermediate and final cube shapes. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/Å²·s.

Movie S8. TEM movie of dissolution of an additional gold rhombic dodecahedron exhibiting the tetrahexahedron transient intermediate and final cube shapes. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/Å²·s.

Movie S29. Monte Carlo simulation movie of a rhombic dodecahedral, 7-million-atom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon} = -6.5$. The number of attempted Monte Carlo steps was ~1.24 × 10⁸, and the acceptance ratio was ~5.04 × 10⁻². The nanocrystal is viewed along the $\langle 110 \rangle$ zone axis.

Movie S30. Monte Carlo simulation movie of a rhombic dodecahedral, 7-million-atom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon} = -6.5$. The number of attempted Monte Carlo steps was ~1.24 × 10⁸, and the acceptance ratio was ~5.04 × 10⁻². The nanocrystal is viewed along the $\langle 110 \rangle$ zone axis and the atoms are color-coded according to their coordination numbers.

Movie S31. Monte Carlo simulation movies of a rhombic dodecahedral, 7-million-atom nanocrystal etched at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon}$ = -5.0, -5.98, -6.0, -6.25, -6.5, -6.75, -7.0, -8.0. The numbers of attempted Monte Carlo steps were: ~2 × 10⁸, 2 × 10¹⁰, 2.23 × 10⁹, 1.34 × 10⁸, 1.24 × 10⁸, 1.17 × 10⁸, 6.45 × 10⁷, 3.60 × 10⁷, respectively, and the corresponding acceptance ratios were: ~3.69 × 10⁻², 1.21 × 10⁻², 3.43 × 10⁻², 5.00 × 10⁻², 5.04 × 10⁻², 5.60 × 10⁻², 0.113, 0.179. The nanocrystals are viewed along the $\langle 100 \rangle$ zone axis.

Movie S32. Monte Carlo simulation movies of a rhombic dodecahedral, 7-million-atom nanocrystal etched at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon} = -5.0, -5.98, -6.0, -6.25, -6.5, -6.75, -7.0, -8.0$. The numbers of attempted Monte Carlo steps were: $\sim 2 \times 10^8, 2 \times 10^{10}, 2.23 \times 10^9, 1.34 \times 10^8, 1.24 \times 10^8, 1.17 \times 10^8, 6.45 \times 10^7, 3.60 \times 10^7,$ respectively, and the corresponding acceptance ratios were: $\sim 3.69 \times 10^{-2}, 1.21 \times 10^{-2}, 3.43 \times 10^{-2}, 5.00 \times 10^{-2}, 5.04 \times 10^{-2}, 5.60 \times 10^{-2}, 0.113, 0.179$. The nanocrystals are viewed along the $\langle 110 \rangle$ zone axis.

Movie S33. Monte Carlo simulation movies of a rhombic dodecahedral, 7-million-atom nanocrystal etched at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon} = -5.0, -5.98, -6.0, -6.25, -6.5, -6.75, -7.0, -8.0$. The numbers of attempted Monte Carlo steps were: $\sim 2 \times 10^8, 2 \times 10^{10}, 2.23 \times 10^9, 1.34 \times 10^8, 1.24 \times 10^8, 1.17 \times 10^8, 6.45 \times 10^7, 3.60 \times 10^7,$ respectively, and the corresponding acceptance ratios were: $\sim 3.69 \times 10^{-2}, 1.21 \times 10^{-2}, 3.43 \times 10^{-2}, 5.00 \times 10^{-2}, 5.04 \times 10^{-2}, 5.60 \times 10^{-2}, 0.113, 0.179$. The nanocrystals are viewed along the $\langle 100 \rangle$ zone axis and the atoms are color-coded according to their coordination numbers.

Movie S34. Monte Carlo simulation movies of a rhombic dodecahedral, 7-million-atom nanocrystal etched at different values of the chemical potential: from left-to-right, top-to-bottom $\frac{\mu}{\epsilon} = -5.0, -5.98, -6.0, -6.25, -6.5, -6.75, -7.0, -8.0$. The numbers of attempted Monte Carlo steps were: $\sim 2 \times 10^8, 2 \times 10^{10}, 2.23 \times 10^9, 1.34 \times 10^8, 1.24 \times 10^8, 1.17 \times 10^8, 6.45 \times 10^7, 3.60 \times 10^7,$ respectively, and the corresponding acceptance ratios were: $\sim 3.69 \times 10^{-2}, 1.21 \times 10^{-2}, 3.43 \times 10^{-2}, 5.00 \times 10^{-2}, 5.04 \times 10^{-2}, 5.60 \times 10^{-2}, 0.113, 0.179$. The nanocrystals are viewed along the $\langle 110 \rangle$ zone axis and the atoms are color-coded according to their coordination numbers.

Movie S35. TEM movie of simultaneous dissolution of a gold rhombic dodecahedron and cube exhibiting the tetrahexahedron transient intermediate shape. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/Å²·s.

Movie S36. TEM movie of partial dissolution of a gold triangular prism followed by surface refaceting and homogeneous nucleation of small gold nanocrystals. The concentration of FeCl₃ was 0.02 M in the GLC loading solution, which was prepared by mixing 0.3 mL of 0.1 M acidified FeCl₃ and 1.2 mL of 0.01 M Tris buffer solution. The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/Å²·s.

Movie S37. Contour plot movie showing the progression of nanocrystal local curvature for the equilibrium triangular prism dissolution reaction shown in Movie S36. Five contours are shown at any given time to better illustrate the development of low-energy blunt facets.

Movie S38. TEM movie of dissolution of a gold triangular prism exhibiting a complex transient intermediate morphology. The acquisition frame rate is 2.5 fps. The electron dose rate was 86 electrons/ $Å^2$ ·s.

Movie S39. TEM movie of dissolution of an additional gold triangular prism exhibiting a complex transient intermediate morphology. The acquisition frame rate is 5.0 fps. The electron dose rate was 86 electrons/Å²·s.

Movie S40. Monte Carlo simulation movies of a cubic, 1-, 7- and 55-million-atom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon}$ = -6.5. The numbers of attempted Monte Carlo steps were: ~1.94 × 10⁷, 1.34 × 10⁸, 1.10 × 10⁹, respectively, and the corresponding acceptance ratios were: ~5.56 × 10⁻², 5.24 × 10⁻², 5.06 × 10⁻². The nanocrystals are viewed along the (100) zone axis. For the three movies at the bottom, the atoms are color-coded according to their coordination numbers.

Movie S41. Monte Carlo simulation movies of a rhombic dodecahedral, 1-, 7- and 55-millionatom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon}$ = -6.5. The numbers of attempted Monte Carlo steps were: ~2.03 × 10⁷, 1.24 × 10⁸, 1.05 × 10⁹, respectively, and the corresponding acceptance ratios were: ~5.33 × 10⁻², 5.04 × 10⁻², 4.77 × 10⁻². The nanocrystals are viewed along the (100) zone axis. For the three movies at the bottom, the atoms are color-coded according to their coordination numbers.

Movie S42. Monte Carlo simulation movies of a rhombic dodecahedral, 1-, 7- and 55-millionatom nanocrystal etched at the chemical potential $\frac{\mu}{\epsilon}$ = -6.5. The numbers of attempted Monte Carlo steps were: ~2.03 × 10⁷, 1.24 × 10⁻² 1.05 × 10⁹, respectively, and the corresponding acceptance ratios were: ~5.33 × 10⁻², 5.04 × 10⁻², 4.77 × 10⁻². The nanocrystals are viewed along the $\langle 110 \rangle$ zone axis. For the three movies at the bottom, the atoms are color-coded according to their coordination numbers.

Movie S43. TEM movie of rapid dissolution of a gold cube. The acquisition frame rate is 2.5 fps. The electron dose rate was 217 electrons/ $Å^2 \cdot s$.

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